

AMENDMENT UNDER 37 C.F.R. § 1.116 EXPEDITED PROCEDURE GROUP 2826 PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Docket No: Q77191

Koichi OHTO, et al.

Appln. No.: 10/650,193

Group Art Unit: 2826

Confirmation No.: 6245

Examiner: Alexander O. WILLIAMS

Filed: August 28, 2003

For:

SEMICONDUCTOR DEVICE HAVING SILICON-DIFFUSED METAL WIRING

LAYER AND ITS MANUFACTURING METHOD

SUPPLEMENTAL AMENDMENT UNDER 37 C.F.R. § 1.116

MAIL STOP AF

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In response to the Advisory Action dated November 22, 2006, please amend the aboveidentified application as follows on the accompanying pages.

TABLE OF CONTENTS

AMENDMENTS TO THE SPECIFICATION	2
AMENDMENTS TO THE CLAIMS	7
	•••
REMARKS	c
REMARKS	9